

Stress determination of micromembranes using laser vibrometry

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ABSTRACT

A laser vibrometry based dynamic technique for biaxial residual stress determination in micromembranes is reported. Layered, low pressure chemical vapor deposition (LPCVD) grown, rectangular shaped micromembranes are ultrasonically excited. The resulting micromembrane displacement, as a function of frequency and position, is recorded to yield resonance frequencies and associated vibrational mode numbers. The stress is determined from this information. Vibrations forced from ultrasonic pressure (-25 Pa) resulted in peak displacements of tens of nanometers at resonance. For the sample set studied the (3,1) mode resonance peak displayed the least damping in atmospheric testing and was used to establish stress levels - 10^8 N/m². A trend for this stress showing an overall decrease by -40% as a result of thermomechanical cycling was identified.

INTRODUCTION

The emergence of **micromembrane-based** architectures has resulted in a need for accurate analysis of membrane stress characteristics. **Micromembranes** are increasingly being used for diverse applications such as x-ray lithography masks [1-4] and microwave transmission lines. Examples of membrane-based microwave components include switches, very **high-Q** inductors, **Ka-band** power dividers, and filters operating from 15 **GHz** to 250 GHz [5-9]. In order to successfully implement these structures in non-laboratory environments, it is important to investigate the residual biaxial stress build-up during fabrication, and the subsequent evolution of the stress with **thermomechanical** cycling. This knowledge is critical if one is to resolve and correct for stress-related failure mechanisms. Electronic components using membrane technology are increasingly being envisaged for miniaturization of future space flight hardware, here too, mechanical property dependence on structural vibrations and thermal cycling is crucial for reliable implementation.

Previous work on membrane stress characterization includes both theoretical and experimental methods. Analytical and finite element stress analysis of homogeneous, rectangular and circular membranes [10,11] can predict the biaxial stress and Young's modulus of membranes. Studies of stress and Young's modulus by static (load versus deflection) measurement methods have also been reported [11,12]. In addition, dynamic techniques have been used where the resonant frequencies of vibrating membranes are used (as elaborated below) for determining stress [1,13].

A new dynamic technique for membrane stress determination utilizing laser vibrometry is described in the present report. Specifically, a tightly focused laser spot is used for interrogating the driven (vibrating) membrane surface while extracting displacement and velocity spot measurements from an interferometric analysis of the retro-reflection. The technique allows a comprehensive characterization of vibrating micromembranes and can

potentially accommodate non-standard geometry's, layered micromembrane architecture's and a variety of in-situ monitoring scenarios where evolution of stress is of interest.

Based on membrane vibration theory [14,15] the driven rectangular membrane exhibits resonance's at frequencies f_{mn} given by the relation:

$$f_{mn} = \frac{1}{2} \sqrt{\frac{\sigma}{\rho} \left[\frac{m^2}{lx^2} + \frac{n^2}{ly^2} \right]}^{0.5} \quad (1)$$

where σ and ρ are biaxial stress and density, while lx and ly represent rectangular membrane dimensions. A frequency sweep with the laser vibrometer while recording displacement yields f_{mn} , while modal analysis of individual peaks identifies m and n . Knowing lx , ly , m , n and ρ allows a reliable determination of the stress, σ .

Measured frequencies are altered due to atmospheric loading and a suggested correction [1] which takes this into account is:

$$f_{mn} = (f_{mn})_{air} \left[1 + 1.34 \left(\frac{l \rho_{air}}{t \rho} \right) \right] \quad (2)$$

where l is defined as $\sqrt{(lx \cdot ly)}$, t is membrane thickness and ρ_{air} is air density.

EXPERIMENTAL

The type of micromembrane examined in this study consists of a thin-film coplanar waveguide (CPW) transmission line which is supported on a three-layer dielectric membrane. The membrane is grown on a silicon wafer, and comprises a high temperature oxide (HTO) and subsequent silicon nitride and oxide layers. Each of the top layers is

deposited using low pressure chemical vapor deposition (LPCVD). By properly balancing the thickness of the three layers, a composite in slight tension is obtained which remains rigid when portions of the silicon substrate are removed. High-yield membranes are obtained on 10 cm diameter, 500-550 micrometers thick wafers using thicknesses of 750/350/450 nm for the thermal oxide, intermediate nitride, and top oxide layers, respectively. Gold metallization 1 to 1.2 micrometers thick covers 95 percent of the membrane surface. Figure 1 shows the shape and dimensions of micromembranes used in the present study.

Dynamic testing of the micromembranes was carried out at atmospheric pressure using the experimental arrangement shown in Figure 2. Samples were mounted on a rigid support using double sided adhesive, with the focused spot from the laser vibrometer incident on the micromembrane. Micro-translation of the micromembrane with respect to the incident laser spot was possible. The sample mount, laser vibrometer and audio speaker were supported on an air table to minimize noise from extraneous vibrations. Pressure fluctuations generated by the audio speaker (JBL Model 4370) excited vibrations over a frequency range 15-60 KHz.

The laser vibrometer manufactured by Polytec PI Inc. (Model OFV-302) utilizes an integrated Mach-Zender interferometer. Separate displacement and velocity mode outputs are derived after appropriate processing of the optical interference signal derived from the retro-reflection. The corroboration of results using the two modes was checked and found to be excellent, though, the displacement mode was used for all the measurements. Absolute displacement and velocity determination relies on instrument constants. The reliability of the conversion constant was verified for displacements ranging from 100 nm - 2 micrometers, @ 500 Hz, using a magnetostrictive device where the current versus

displacement was known. The displacement bandwidth is 80 KHz and flat in the region of interest.

A digital signal analyzer (DSA) (HP Model 3562A) was used to perform a linear sine sweep (resolution 25 Hz) of the micromembrane response. A sinusoidal source signal with a fixed amplitude (100 mV peak to peak), from the DSA, is simultaneously applied to channel 1 of the DSA and the audio amplifier driving the speaker. The laser vibrometer analog displacement output is fed to channel 2 of the DSA and the ratio of power spectra (PS channel 1 to PS channel 2) is recorded. PS channel 1 is flat since it originates from a fixed amplitude sinusoidal signal thereby serving as a reliable reference. Variations in PS channel 2 represent relative membrane displacement as a function of frequency. Identical frequency sweeps performed with a 1/4" microphone (Bruel and Kjaer, Model 4135) positioned at the location of the membrane were used, to correct for frequency dependent variations in audio amplifier gain and speaker output. The microphone response allowed an estimate of the peak pressure driving the micromembranes and this was -25 Pa.

Both membrane and microphone response were verified to be linear for the speaker output levels used, The laser vibrometer was unable to sense any displacement from regions of the substrate along the boundary ensuring that significant translational motion of the substrate/membrane assembly did not occur. Laser vibrometer output recorded in the absence of excitation indicated that the noise floor was 2-3 orders of magnitude below the membrane driven response.

RESULTS

Three sets of micromembranes with different thermomechanical histories, as elaborated in Table 1, were tested. Random vibration testing for 180 second durations were conducted along the three principle axes of the membranes. Vibration frequencies ranged from 20-2000 Hz and levels up to $0.8 \text{ g}^2/\text{Hz}$ were used. Thermal cycle time was 1 hour.

Figure 3 shows the swept sine response, for a “big” and “small” membrane (see Fig. 1). Resonance peaks are shifted to higher frequencies for the smaller dimensioned membranes, as expected. The presence of an initial broad peak followed by sharper peaks was typical of all the samples tested.

A modal analysis of the first sharp, well defined peak was undertaken by translating the micromembrane with respect to the focused laser spot, while driving the membrane at the resonance frequency. The peak of the averaged power spectrum, measured by the DSA, was converted to membrane displacement. The results, shown as the surface plot of Figure 4, clearly indicate a $m=3$, $n=1$ mode. Maximum displacements of 80 nm and minimum displacements of 3 nm were detected. Reliability of these absolute numbers is subject to the conversion constants discussed above. The observed displacements could not be verified by computation since this would entail a knowledge of the damping forces operative and ascertaining this parameter was beyond the scope of the present study.

Micromembrane dimensions (see Fig. 1): $l_x = 7.8 \text{ mm}$, $l_y = 2.5 \text{ mm}$ and $l_x = 5.04 \text{ mm}$, $l_y = 1.2 \text{ mm}$ were measured for the big and small samples. A weighted micromembrane density, $\rho = 10083 \text{ Kg/m}^3$, was calculated based on the relative thickness of SiO_2 , Si_3N_4 and Au. Using these values and the peak frequency, f_{31} the stresses for each membrane were calculated. Mode numbers for other observed peaks in the swept sine spectra were

compared to calculated values using the method of ratios f_{mn}/f_{31} . A complete summary of determined stress using the correction given by equation (2) and the accompanying mode assignments along with % deviation from calculated values is presented in Table 2. The modes for the peaks observed in Figure 3 are also shown.

A general trend observed in all the measurements is the highly damped and poorly defined nature of the fundamental (1,1) peak, This observation is further exaggerated for the smaller membranes as shown in Figure 3. The (3,1) mode, however, appears to be a relatively high quality factor resonance and is better suited for reliable stress determination than the lower order modes. A survey of Table 2 also shows other inexplicable features, such as: (i) the membranes tested display odd numbered modes such as (5,1) (7,1) and (9,1) while corresponding, even m, modes do not appear; (ii) The uncertainty in identifying the modes lower than (3,1) is higher than that encountered for higher order modes; (iii) modes such as (4,3) and (5,3) seem to appear in one of the samples with many intermediate modes being suppressed. Observations of this nature were not found in previous reports.

Finally, Figure 5 shows a summary of the residual biaxial stress obtained for the entire sample set. The derived stress is displayed as a function of the number of thermal cycles. An overall trend of reduction in stress as a result of thermomechanical processing is observed. The error bars shown were chosen to be ~ 7% based on uncertainties in the membrane thickness and dimensions. The conjecture can be made that the combination of mechanical and thermal cycling brings about a lowering of the clamping force at the membrane boundaries due to differential thermal expansion and elastic coefficients between the membrane and substrate.

CONCLUSION

The main significance of the work reported here is the demonstration of a new technique for convenient mechanical characterization of membranes. Spatially localized displacement versus frequency measurements, by pointing a focused laser beam at a vibrating membrane surface, is reported. The technique is potentially applicable to a wide range of scenarios demanding non-invasive stress determination. By measuring the stress as a function of temperature, thermal expansion coefficients of membranes can be inferred. Supplemented by finite element modelling, the technique can be extended to accommodate stresses for layered structures, non-standard geometries and a variety of metallization patterns. Questions and conjectures brought to light by the present study deserve further investigation.

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Table 1: The thermomechanical history of the sample set used for performing stress measurements.

Table 2: A summary of observed frequency peaks, mode assignments, percentage deviations between expected and observed peak positions and derived biaxial stress for the entire sample set studied.

LIST OF FIGURES

Figure 1: Schematic view of the membranes, with dimensions in mm, supported by Si substrate (hatched region). The membrane outline is shown by dashed lines while the **metallization** outline is shown by dark lines, Details of the gold pattern overlay covering 95% of the membranes are not shown.

Figure 2: A schematic layout of the experimental arrangement used to perform the vibrational analysis of the membranes.

Figure 3: (a) Displacement spectrum of a large membrane sample (7.8 x 2.5 mm, sample set 3). (b) Displacement spectrum of small (5.04 x 1.2 mm, sample set 3).

Figure 4: Surface plot showing the spatial variation of displacement for a (3, 1) resonance.

Figure 5: Plot showing the evolution of stress as a function of thermal cycles. Vibration testing was also performed on the samples (see Table 1).

Table 1

Set 1	As received
Set 2	Vibration tested, 100 thermal cycles (208 K to 423 K)
Set 3	100 thermal cycles (208 K to 423 K), vibration testing, 100 thermal cycles (208 K to 423 K)

Table 2

Sample	Observed Frequency (Hz)	Mode Number	% Deviation	Stress (N/m²)
7.8 x 2.5 mm Set 1	23333	(1,1)	1.7	2,13x10 ⁸
	26032	(2,1)	3	
	31349	(3,1)	-	
	42460	(5,1)	0.5	
	55159	(7,1)	0.7	
5.04 x 1.2 Set 1	41746	(1,1)	0.7	1.78x10 ⁸
	50317	(3,1)		
7.8 x 2.5 mm Set 2	23452	(1,1)	4.7	1.89 x 10 ⁸
	26349	(2,1)	4	
	29523	(3,1)		
	40238	(5,1)	0°3	
	52460	(7,1)		
5.04 x 1.2 mm Set 2	50159	(1,1)	1.7	1.80x 10 ⁸
	58968	(3,1)		
7.8 x 2.5 mm Set 3	17780	(1,1)	1.4	1.16x 10 ⁸
	23161	(3,1)	-	
	31323	(5,1)	0.7	
	40471	(7,1)	1.35	
	50157	(9,1)	1.6	
	54013	(4,3)	0.8	
	55807	(5,3)	1.6	
5.04 x 1.3 mm Set 3	37242	(1,1)	2.1	1.07 x 10 ⁸
	40022	(2,1)	2.4	
	45493	(3,1)	-	
	59036	(5,1)	2.5	









